## Information Disclosure Statement By Applicant Substitute for form 1449/PTO

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Splication Number: 10/776,144 Filing Date: 02/10/2004

First Named Inventor: Johnson

Art Unit: 2818 Examiner Name:

Attorney Docket Number: MJ 2004-2

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Examiner

Examiner Signature: Aukuong

Considered: 10/04



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Signature: See Andrewry

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